Low-ohmic single-pole double-throw analog switch

Rev. 07 — 21 January 2010

Product data sheet

1. General description

The NX3L1T3157 is a low-ohmic single-pole double-throw analog switch suitable for use as an analog or digital 2:1 multiplexer/demultiplexer. It has a digital select input (S), two independent inputs/outputs (Y0 and Y1) and a common input/output (Z).

Schmitt trigger action at the digital input makes the circuit tolerant to slower input rise and fall times. Low threshold digital input allows this device to be driven by 1.8 V logic levels in 3.3 V applications without significant increase in supply current I_{CC}. The NX3L1T3157 allows signals with amplitude up to V_{CC} to be transmitted from Z to Y0 or Y1, or from Y0 or Y1 to Z. Its low ON resistance (0.5 Ω) and flatness (0.13 Ω) ensures minimal attenuation and distortion of transmitted signals.

2. Features

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
 - 1.6 Ω (typical) at V_{CC} = 1.4 V
 - 1.0 Ω (typical) at V_{CC} = 1.65 V
 - 0.55 Ω (typical) at V_{CC} = 2.3 V
 - 0.50 Ω (typical) at V_{CC} = 2.7 V
 - 0.50 Ω (typical) at V_{CC} = 4.3 V
- Break-before-make switching
- High noise immunity
- ESD protection:
 - HBM JESD22-A114E Class 3A exceeds 7500 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM AEC-Q100-011 revision B exceeds 1000 V
 - IEC61000-4-2 contact discharge exceeds 8000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level A
- 1.8 V control logic at V_{CC} = 3.6 V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V_{CC}
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



Low-ohmic single-pole double-throw analog switch

3. Applications

- Cell phone
- PDA
- Portable media player

4. Ordering information

Table 1.Ordering information

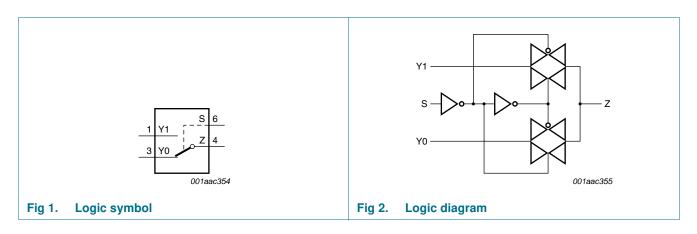
Type number	Package										
	Temperature range Name Description										
NX3L1T3157GW	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363							
NX3L1T3157GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm	SOT886							

5. Marking

Table 2.	Marking codes ^[1]	
Type num	nber	Marking code
NX3L1T3	157GW	MI
NX3L1T3	157GM	MI

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

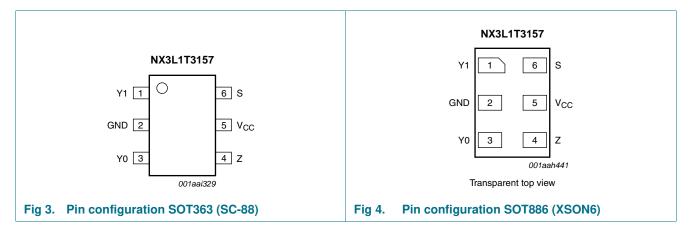
6. Functional diagram



Low-ohmic single-pole double-throw analog switch

7. Pinning information

7.1 Pinning



7.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
Y1	1	independent input or output
GND	2	ground (0 V)
Y0	3	independent input or output
Z	4	common output or input
V _{CC}	5	supply voltage
S	6	select input

8. Functional description

Table 4.Function table

Input S	Channel on
L	YO
Н	Y1

[1] H = HIGH voltage level; L = LOW voltage level.

Low-ohmic single-pole double-throw analog switch

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage	select input S	<u>[1]</u> –0.5	+4.6	V
V _{SW}	switch voltage		<u>[2]</u> –0.5	$V_{CC} + 0.5$	V
I _{IK}	input clamping current	$V_{l} < -0.5 V$	-50	-	mA
I _{SK}	switch clamping current	$V_{l} < -0.5$ V or $V_{l} > V_{CC}$ + 0.5 V	-	±50	mA
I _{SW}	switch current	V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; source or sink current	-	±350	mA
		V _{SW} > -0.5 V or V _{SW} < V _{CC} + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	<u>[3]</u> _	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For SC-88 package: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K. For XSON6 package: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		1.4	4.3	V
VI	input voltage	select input S	0	4.3	V
V _{SW}	switch voltage		<u>[1]</u> 0	V _{CC}	V
T _{amb}	ambient temperature		-40	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$	[2] _	200	ns/V

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Yn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

Low-ohmic single-pole double-throw analog switch

11. Static characteristics

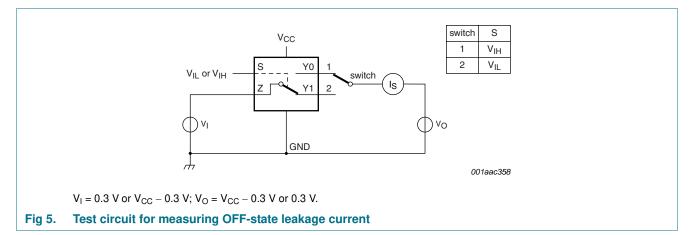
Table 7. Static characteristics

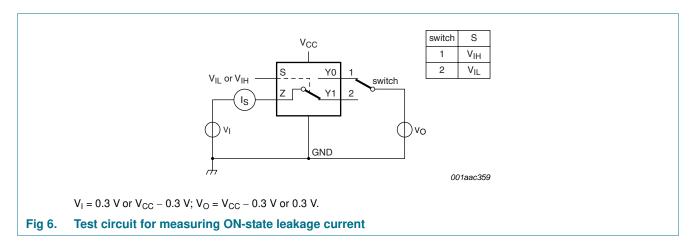
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	Τ _ε	_{amb} = 25	°C	T _{amb} =	–40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
V _{IH}	HIGH-level	V _{CC} = 1.4 V to 1.6 V	0.9	-	-	0.9	-	-	V
	input voltage	V _{CC} = 1.65 V to 1.95 V	0.9	-	-	0.9	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.1	-	-	1.1	-	-	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	1.3	-	-	1.3	-	-	V
		$V_{CC} = 3.6 V \text{ to } 4.3 V$	1.4	-	-	1.4	-	-	V
V _{IL}	LOW-level	V _{CC} = 1.4 V to 1.6 V	-	-	0.3	-	0.3	0.3	V
	input voltage	V _{CC} = 1.65 V to 1.95 V	-	-	0.4	-	0.4	0.3	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.4	-	0.4	0.4	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.5	-	0.5	0.5	V
		V _{CC} = 3.6 V to 4.3 V	-	-	0.6	-	0.6	0.6	V
I	input leakage current	select input S; V _I = GND to 4.3 V; V _{CC} = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	μA
$I_{S(OFF)}$	OFF-state leakage	Y0 and Y1 port; see <u>Figure 5</u>							
	current	$V_{CC} = 1.4 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	±5	-	±50	±500	nA
		$V_{CC} = 3.6 V \text{ to } 4.3 V$	-	-	±10	-	±50	±500	nA
I _{S(ON)}	ON-state	Z port; see Figure 6							
	leakage current	$V_{CC} = 1.4 \text{ V} \text{ to } 3.6 \text{ V}$	-	-	± 5	-	±50	±500	nA
	current	$V_{CC} = 3.6 V \text{ to } 4.3 V$	-	-	±10	-	±50	±500	nA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{SW} = GND$ or V_{CC}							
		$V_{CC} = 3.6 V$	-	-	100	-	690	6000	nA
		$V_{CC} = 4.3 V$	-	-	150	-	800	7000	nA
ΔI_{CC}	additional	$V_{SW} = GND \text{ or } V_{CC}$							
	supply current	$V_{I} = 2.6 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	2.0	4.0	-	7	7	μA
		$V_{I} = 2.6 \text{ V}; V_{CC} = 3.6 \text{ V}$	-	0.35	0.7	-	1	1	μA
		$V_{I} = 1.8 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	7.0	10.0	-	15	15	μA
		$V_{I} = 1.8 \text{ V}; V_{CC} = 3.6 \text{ V}$	-	2.5	4.0	-	5	5	μA
		$V_{I} = 1.8 \text{ V}; V_{CC} = 2.5 \text{ V}$	-	50	200	-	300	500	nA
CI	input capacitance		-	1.0	-	-	-	-	pF
$C_{S(OFF)}$	OFF-state capacitance		-	35	-	-	-	-	pF
C _{S(ON)}	ON-state capacitance		-	130	-	-	-	-	pF

Low-ohmic single-pole double-throw analog switch

11.1 Test circuits





Low-ohmic single-pole double-throw analog switch

11.2 ON resistance

Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 8 to Figure 14.

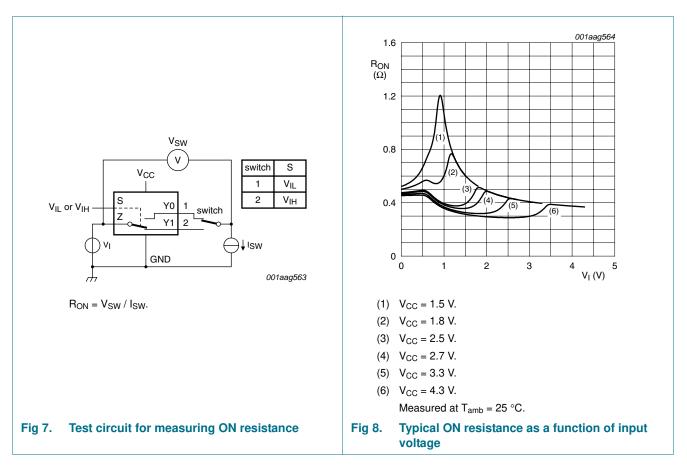
Symbol	Parameter	Conditions	T _{amb} =	: −40 °C to	o +85 °C	T_{amb} = -40 °	C to +125 °C	Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Max	
R _{ON(peak)}	ON resistance (peak)	$V_I = GND$ to V_{CC} ; $I_{SW} = 100$ mA; see Figure 7						
		$V_{CC} = 1.4 V$	-	1.6	3.7	-	4.1	Ω
		V _{CC} = 1.65 V	-	1.0	1.6	-	1.7	Ω
		$V_{CC} = 2.3 V$	-	0.55	0.8	-	0.9	Ω
		$V_{CC} = 2.7 V$	-	0.5	0.75	-	0.9	Ω
		$V_{CC} = 4.3 V$	-	0.5	0.75	-	0.9	Ω
ΔR_{ON}	ON resistance mismatch between channels	$V_{I} = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA}$	<u>2]</u>					
		$V_{CC} = 1.4 V$	-	0.04	0.3	-	0.3	Ω
		V _{CC} = 1.65 V	-	0.04	0.2	-	0.3	Ω
		$V_{CC} = 2.3 V$	-	0.02	0.08	-	0.1	Ω
		$V_{CC} = 2.7 V$	-	0.02	0.075	-	0.1	Ω
		$V_{CC} = 4.3 V$	-	0.02	0.075	-	0.1	Ω
R _{ON(flat)}	ON resistance (flatness)	$V_{I} = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA}$	3]					
		$V_{CC} = 1.4 V$	-	1.0	3.3	-	3.6	Ω
		V _{CC} = 1.65 V	-	0.5	1.2	-	1.3	Ω
		$V_{CC} = 2.3 V$	-	0.15	0.3	-	0.35	Ω
		$V_{CC} = 2.7 V$	-	0.13	0.3	-	0.35	Ω
		$V_{CC} = 4.3 V$	-	0.2	0.4	-	0.45	Ω

[1] Typical values are measured at T_{amb} = 25 °C.

[2] Measured at identical V_{CC} , temperature and input voltage.

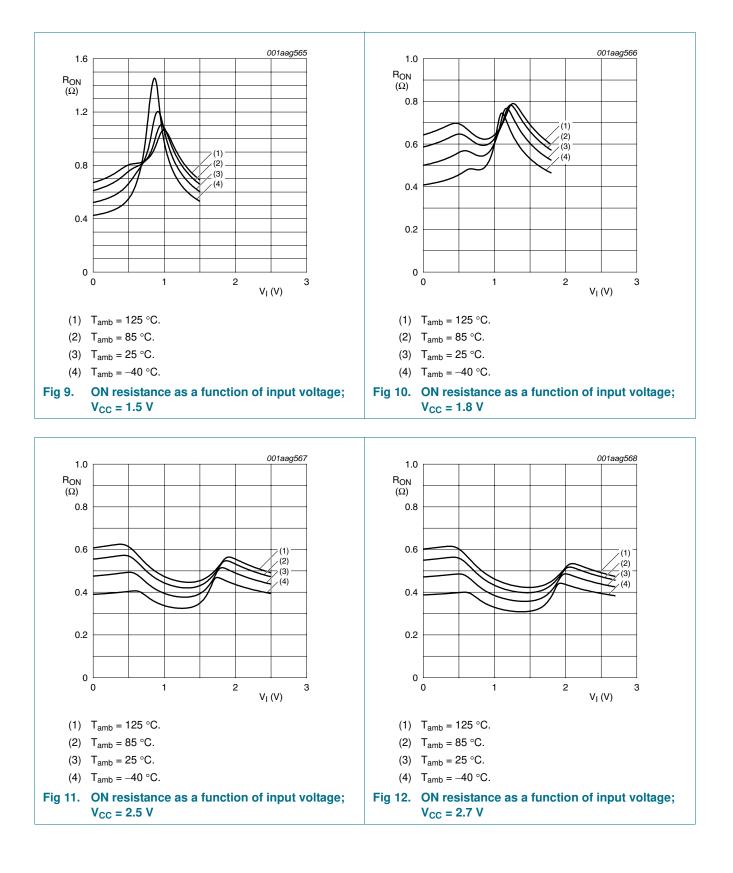
[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and temperature.

Low-ohmic single-pole double-throw analog switch



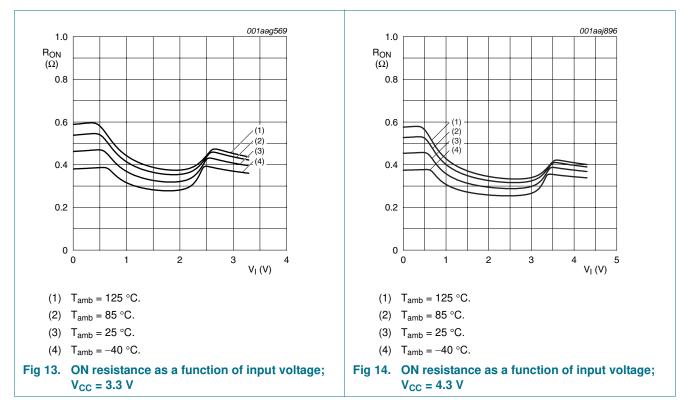
11.3 ON resistance test circuit and graphs

NX3L1T3157



NX3L1T3157

Low-ohmic single-pole double-throw analog switch



12. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 17.

Symbol	Parameter	Conditions		25 °C		-40	°C to +12	5 °C	Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Мах (85 °С)	Max (125 °C)	
t _{en}	enable time	S to Z or Yn; see <u>Figure 15</u>							
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	-	50	90	-	120	120	ns
		V _{CC} = 1.65 V to 1.95 V	-	36	70	-	80	90	ns
		V_{CC} = 2.3 V to 2.7 V	-	24	45	-	50	55	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	22	40	-	45	50	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	22	40	-	45	50	ns
t _{dis}	disable time	S to Z or Yn; see <u>Figure 15</u>							
		$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$	-	32	70	-	80	90	ns
		V _{CC} = 1.65 V to 1.95 V	-	20	55	-	60	65	ns
		V_{CC} = 2.3 V to 2.7 V	-	12	25	-	30	35	ns
		$V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$	-	10	20	-	25	30	ns
		V_{CC} = 3.6 V to 4.3 V	-	10	20	-	25	30	ns

Low-ohmic single-pole double-throw analog switch

Symbol	DIParameterConditions25 °C			–40 °C to +125 °C			Unit			
				Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	-
t _{b-m} break-before-make time	see Figure 16	[2]								
	time	V _{CC} = 1.4 V to 1.6 V		-	19	-	9	-	-	ns
		V _{CC} = 1.65 V to 1.95 V		-	17	-	7	-	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-	13	-	4	-	-	ns
		V _{CC} = 2.7 V to 3.6 V		-	10	-	3	-	-	ns
		V _{CC} = 3.6 V to 4.3 V		-	10	-	2	-	-	ns

Table 9. Dynamic characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 17.

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.5 V, 1.8 V, 2.5 V, 3.3 and 4.3 V respectively.

[2] Break-before-make guaranteed by design.

12.1 Waveform and test circuits

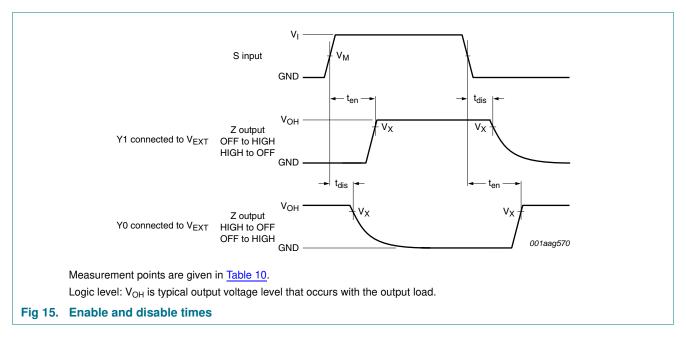
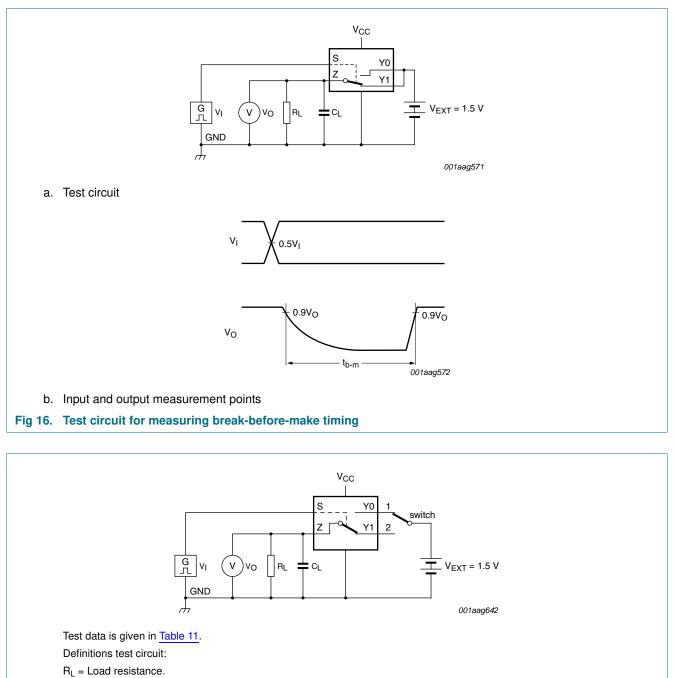


Table 10. Measurement points

Supply voltage	Input	Output
V _{cc}	V _M	V _X
1.4 V to 4.3 V	0.5V _{CC}	0.9V _{OH}

NX3L1T3157

Low-ohmic single-pole double-throw analog switch



C_L = Load capacitance including jig and probe capacitance.

 V_{EXT} = External voltage for measuring switching times.

Fig 17. Load circuit for switching times

Table 11. Test data

Supply voltage	Input		voltage Input Load		Load	
V _{cc}	V _I t _r , t _f		CL	RL		
1.4 V to 4.3 V	V _{CC}	≤ 2.5 ns	35 pF	50 Ω		

NX3L1T3157_7 Product data sheet

Low-ohmic single-pole double-throw analog switch

12.2 Additional dynamic characteristics

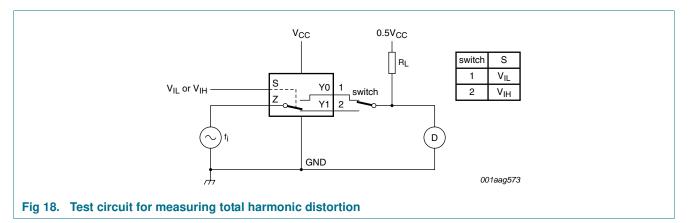
Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_I = GND$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 2.5$ ns; $T_{amb} = 25$ °C.

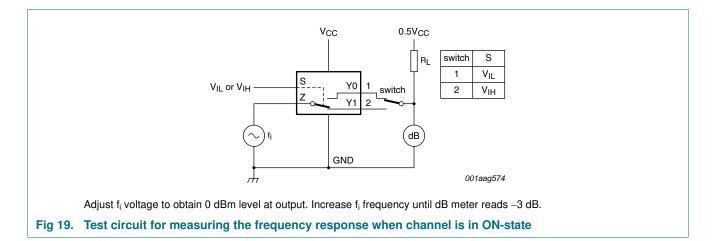
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
THD	total harmonic distortion	f_i = 20 Hz to 20 kHz; R_L = 32 Ω ; see <u>Figure 18</u>	[1]			
		V _{CC} = 1.4 V; V _I = 1 V (p-p)	-	0.15	-	%
		V _{CC} = 1.65 V; V _I = 1.2 V (p-p)	-	0.10	-	%
		V _{CC} = 2.3 V; V _I = 1.5 V (p-p)	-	0.02	-	%
		$V_{CC} = 2.7 \text{ V}; \text{ V}_{I} = 2 \text{ V} (p-p)$	-	0.02	-	%
		$V_{CC} = 4.3 \text{ V}; \text{ V}_{I} = 2 \text{ V} (p-p)$	-	0.02	-	%
$f_{(-3dB)}$	–3 dB frequency response	$R_L = 50 \Omega$; see Figure 19	[1]			
		$V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$	-	60	-	MHz
α_{iso}	isolation (OFF-state)	$f_i = 100 \text{ kHz}; \text{ R}_L = 50 \Omega; \text{ see } \frac{\text{Figure 20}}{100 \text{ kHz}}$	[1]			
		$V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$	-	-90	-	dB
V _{ct}	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$; $C_L = 50 \text{ pF}$; $R_L = 50 \Omega$; see Figure 21				
		V _{CC} = 1.4 V to 3.6 V	-	0.2	-	V
		V _{CC} = 3.6 V to 4.3 V	-	0.3	-	V
Q _{inj}	charge injection	$ f_i = 1 \text{ MHz}; C_L = 0.1 \text{ nF}; R_L = 1 \text{ M}\Omega; V_{gen} = 0 \text{ V}; \\ R_{gen} = 0 \Omega; \text{ see } \frac{\text{Figure 22}}{10000000000000000000000000000000000$				
		$V_{CC} = 1.5 V$	-	3	-	рС
		$V_{CC} = 1.8 V$	-	4	-	рС
		$V_{CC} = 2.5 V$	-	6	-	рС
		V _{CC} = 3.3 V	-	9	-	рС
		$V_{CC} = 4.3 V$	-	15	-	рС

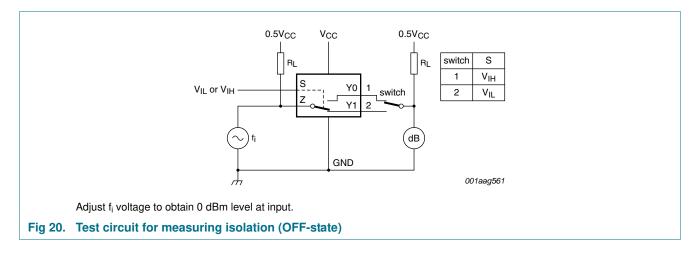
[1] f_i is biased at 0.5V_{CC}.

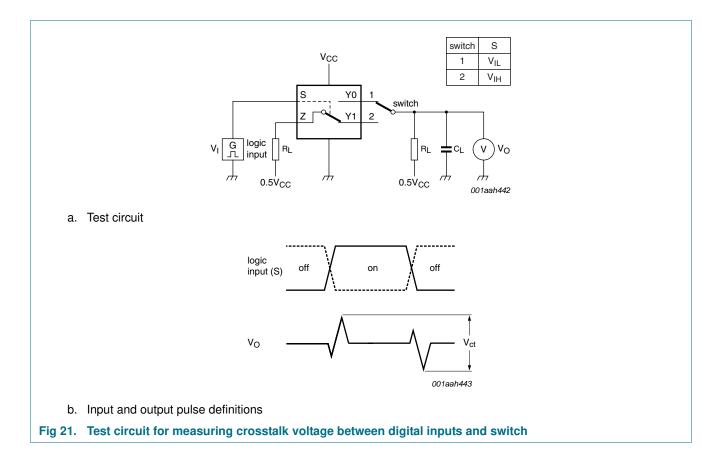
12.3 Test circuits



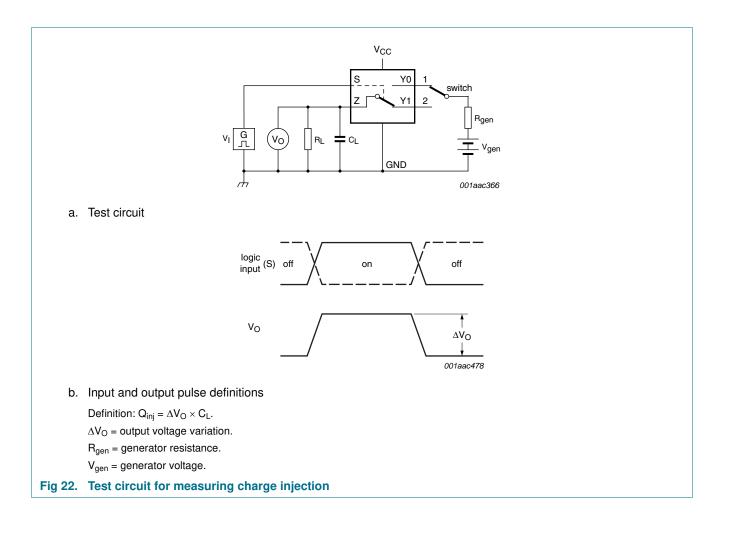
NX3L1T3157







NX3L1T3157



NX3L1T3157

Low-ohmic single-pole double-throw analog switch

13. Package outline

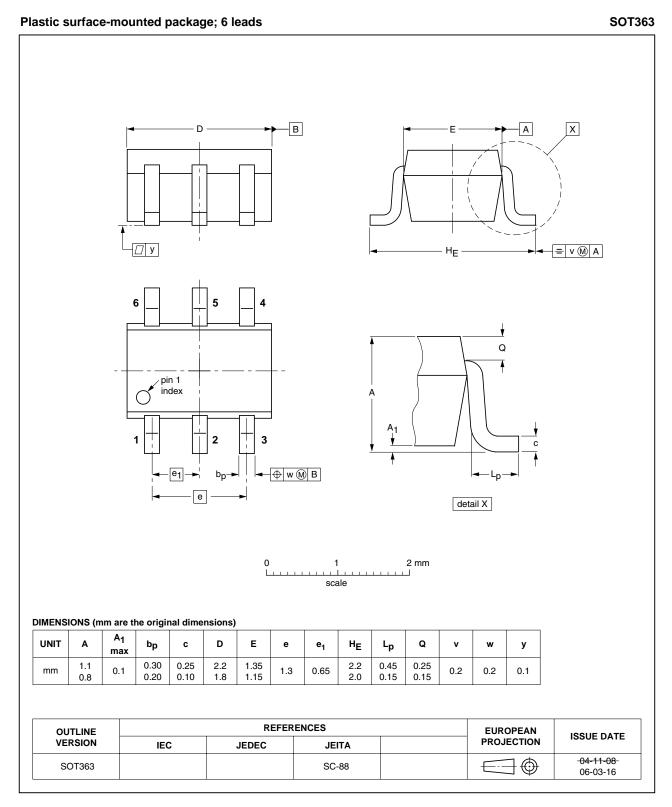


Fig 23. Package outline SOT363 (SC-88)

Low-ohmic single-pole double-throw analog switch

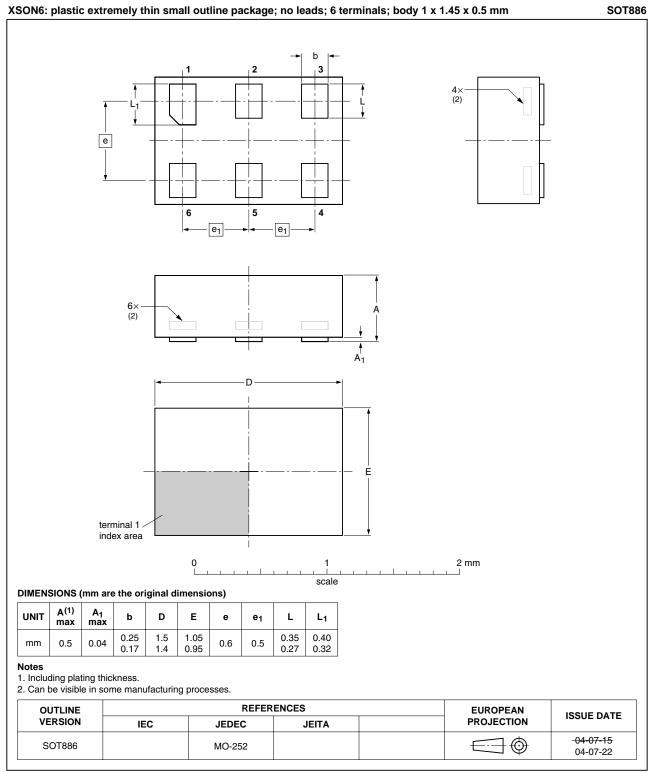


Fig 24. Package outline SOT886 (XSON6)

NX3L1T3157_7 Product data sheet

Low-ohmic single-pole double-throw analog switch

14. Abbreviations

Table 13. Abbreviations			
Acronym	Description		
CDM	Charged Device Model		
CMOS	Complementary Metal-Oxide Semiconductor		
ESD	ElectroStatic Discharge		
HBM	Human Body Model		
MM	Machine Model		
PDA	Personal Digital Assistant		

15. Revision history

Table 14. Revision	history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3L1T3157_7	20100121	Product data sheet	-	NX3L1T3157_6
Modifications:	<u>Section 2</u> : I	EC61000-4-2 added.		
	 <u>Table 8</u>: ON 	l resistance (flatness) chang	ged at V_{CC} = 4.3 V.	
NX3L1T3157_6	20090415	Product data sheet	-	NX3L1T3157_5
NX3L1T3157_5	20080728	Product data sheet	-	NX3L1T3157_4
NX3L1T3157_4	20080718	Product data sheet	-	NX3L1T3157_3
NX3L1T3157_3	20080408	Product data sheet	-	NX3L1T3157_2
NX3L1T3157_2	20080306	Product data sheet	-	NX3L1T3157_1
NX3L1T3157_1	20080103	Product data sheet	-	-

Low-ohmic single-pole double-throw analog switch

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

16.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

16.3 Disclaimers

General — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

16.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

17. Contact information

For more information, please visit: <u>http://www.nxp.com</u>

For sales office addresses, please send an email to: salesaddresses@nxp.com

NX3L1T3157

Low-ohmic single-pole double-throw analog switch

18. Contents

1	General description 1
2	Features 1
3	Applications 2
4	Ordering information 2
5	Marking 2
6	Functional diagram 2
7	Pinning information 3
7.1	Pinning 3
7.2	Pin description 3
8	Functional description 3
9	Limiting values 4
10	Recommended operating conditions 4
11	Static characteristics 5
11.1	Test circuits 6
11.2	ON resistance 7
11.3	ON resistance test circuit and graphs 8
12	Dynamic characteristics 10
12.1	Waveform and test circuits 11
12.2	Additional dynamic characteristics 13
12.3	Test circuits 13
13	Package outline 17
14	Abbreviations 19
15	Revision history 19
16	Legal information 20
16.1	Data sheet status 20
16.2	Definitions 20
16.3	Disclaimers
16.4	Trademarks 20
17	Contact information 20
18	Contents 21

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP B.V. 2010.

All rights reserved.

For more information, please visit: http://www.nxp.com For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 21 January 2010 Document identifier: NX3L1T3157_7

